


 Cite this: *CrystEngComm*, 2025, 27, 4528

Acceleration of scintillation response in Sc,Ca,Mg-codoped YAG:Ce crystals†

 Ia. Gerasymov,^a S. Tkachenko,^a D. Kurtsev,^a D. Kofanov,^a O. Viahin,^a P. Maksimchuk,^a I. Rybalka,^a B. Grynyov,^a J. Delenne,^b L. Martinazzoli,^{b,c} L. Roux,^{b,d} E. Auffray,^b A. Padmanaban^e and O. Sidletskiy^{*,a,e}

 Received 4th April 2025,
 Accepted 27th May 2025

DOI: 10.1039/d5ce00373c

rsc.li/crystengcomm

This study explores fast-timing garnet scintillators as potential candidates for future high-energy physics detectors. Sc-codoped YAG:Ce crystals were successfully grown for the first time using the Czochralski method in a reducing atmosphere from tungsten crucibles. Scintillation decay times were accelerated through codoping of $\text{Y}_3\text{Al}_5\text{O}_{12}:\text{Ce}$ (YAG:Ce) with Sc^{3+} and divalent alkaline earth metal cations (Ca^{2+} , Mg^{2+}). The resulting codoped YAG:Ce exhibited a decay time of 21 ns and a high light yield of 14 000 photons per MeV, making it a strong candidate for future detectors at the HL-LHC, where particle collisions occur every 25 ns. The study also examines correlations between cation substitutions and the optical and scintillation performance of Ce-doped $\text{Al}^{3+}/\text{Sc}^{3+}$ -substituted garnets, comparing them with known counterparts.

1. Introduction

Yttrium aluminum garnet doped with cerium ($\text{Y}_3\text{Al}_5\text{O}_{12}:\text{Ce}$, or YAG:Ce) is a well-established phosphor and scintillation material that has recently regained attention due to advancements in scintillation performance. These improvements include an increased light yield exceeding 33 000 photons per MeV,^{1–3} high radiation tolerance,^{4,5} and cost-effective crystal fabrication technologies.^{6–8}

Despite these advantages, YAG:Ce has limitations for fast-timing applications, such as next-generation high-energy physics experiments at colliders⁹ and time-of-flight positron emission tomography (TOF-PET).^{10,11} Its primary drawback is a relatively slow luminescence decay, with the main component ranging from 55 to 120 ns, alongside slower decay components and afterglow effects.^{11–13} Meanwhile, the high-luminosity large hadron collider (HL-LHC) at CERN operates at a 25 ns⁻¹ collision frequency, requiring scintillation signals to be registered within a <25 ns window to prevent pile-up.¹⁴

In Ce-doped garnets, slow luminescence decay is primarily attributed to the intrinsically long Ce^{3+} lifetime of 50–60 ns in garnet hosts. Additionally, intrinsic lattice defects—such as cationic antisites (A^{3+} and B^{3+} substitutions in the $\text{A}_3\text{B}_5\text{O}_{12}$ lattice), oxygen and Al^{3+} vacancies, and their combinations—contribute to delayed scintillation.^{15,16} Furthermore, garnets grown in CO-containing atmospheres using cost-effective W or Mo crucibles often incorporate carbon-related defects. Interestingly, these defects can enhance scintillation performance by creating negatively charged centers that suppress electron trapping and the formation of color centers associated with positively charged defects.^{17–19}

Reducing luminescence decay time below the intrinsic Ce^{3+} lifetime is only possible by introducing non-radiative processes, which inevitably compromise light output. This can be achieved by substituting Al^{3+} with Ga^{3+} or Sc^{3+} and/or by doping with divalent alkaline earth metals. These modifications influence competing mechanisms of electron ionization from Ce^{3+} 5d excited states into the conduction band, as detailed in.^{20–22} While Ga incorporation reduces decay time, it significantly increases production costs, as gallium-containing garnets (*e.g.*, $\text{Gd}_3\text{Al}_{5-x}\text{Ga}_x\text{O}_{12}:\text{Ce}$, GAGG:Ce) require high-cost Ir crucibles and an inert or weakly oxidizing atmosphere for large-scale growth.⁹ In contrast, Sc^{3+} functions similarly to Ga^{3+} by forming conduction band states *via* its 3d orbitals, thereby reducing the energy gap between the Ce 5d₁ level and the conduction band bottom and inducing non-radiative electron transitions.²² However, unlike Ga_2O_3 , scandium oxide remains stable under reducing conditions, making it suitable for crystal growth in W and Mo crucibles.

^a Institute for Scintillation Materials NAS of Ukraine, Kharkiv, Ukraine.

 E-mail: sidletskiy@isma.kharkiv.ua
^b European Organization for Nuclear Research (CERN), Geneva, Switzerland

^c INFN & Università degli Studi di Milano-Bicocca, Milan, Italy

^d Université Lyon, Université Claude Bernard Lyon 1, Institute Lumière Matière

UMR 5306, CNRS, Villeurbanne, 69100, France

^e Centre of Excellence ENSEMBLE3 Sp. z o. o, Warsaw, 01-919, Poland.

 E-mail: oleg.sidletskiy@ensemble3.eu

 † Electronic supplementary information (ESI) available. See DOI: <https://doi.org/10.1039/d5ce00373c>

10.1039/d5ce00373c



Recent experiments on the crystal growth of Sc-doped garnets have employed various methods, including micro-pulling-down,^{23–25} liquid phase epitaxy (LPE),^{26,27} optical floating zone (OFZ),²⁸ and Bridgman.²⁹ However, each of these techniques has intrinsic limitations that can degrade crystal/film quality and scintillation performance. For instance, the OFZ method introduces high thermal gradients, leading to crystal cracking; the micro-pulling-down technique suffers from radial activator segregation; the Bridgman method often results in compositional inhomogeneities due to poor melt mixing; and LPE-grown films exhibit very low Ce distribution coefficients. These factors likely contribute to the slow scintillation decay and moderate-to-poor light yield observed in these crystals,^{23–29} as discussed in detail in the Discussion section.

The Czochralski method, by contrast, avoids these drawbacks and remains the primary technique for industrial-scale production of many dielectric and semiconductor crystals. Growth of $Y_3Al_{5-x}Sc_xO_{12}$ (YSAG) with Sc contents ranging from 0 to 2 f.u. in the melt using this method has been reported in ref. 30 and 31. The Y_2O_3 – Sc_2O_3 – Al_2O_3 system supports a broad range of garnet-structured solid solutions, though no ternary garnet has been found to melt congruently.³¹ The segregation coefficients $K_{Sc} = 0.83$, $K_{Al} = 1.16$, and $K_Y = 0.96$ (ref. 31) close to unity suggest a relatively uniform distribution of host components along the ingots.

A major advantage of YSAG over $Gd_3Al_{5-x}Sc_xO_{12}$ (GSAG) is its tunable host composition and electronic structure through Sc^{3+} doping. In contrast, GSAG garnet formation is restricted to compositions near the congruently melting $Gd_{2.88}Sc_{1.89}Al_{3.23}O_{12}$.³¹ As a result, prior studies^{22–26,28–30,32} predominantly focus on compositions close to $Gd_3Sc_2Al_3O_{12}$, where Sc^{3+} substitutes Al^{3+} almost exclusively in octahedral sites. The only reported study on Ce-doped GSAG grown by the Czochralski method, dating back to 1994,³² found a decay time of 120 ns but a relatively high light yield under γ -ray excitation—approximately 30% that of NaI:Tl. Additionally, the effect of Sc^{3+} doping on the energy barrier height for $Ce^{3+} 5d_1$ ionization in $Gd_{2.97}Ce_{0.03}Ga_{2.5}Sc_1Al_{1.5}O_{12}$ (GASGG:Ce) was demonstrated in ref. 22.

The acceleration of rise and decay times in Ce-doped rare-earth garnets through the introduction of divalent alkaline-earth metal ions has been extensively studied.^{33–40} When alkaline-earth metals substitute Y^{3+} or Al^{3+} sites, they introduce additional negative charge into the lattice, which is compensated by the partial oxidation of Ce^{3+} to Ce^{4+} . Moreover, Mg^{2+} ions are believed to form complexes with Ce^{3+}/Ce^{4+} , facilitating hole transfer to luminescence centers and thereby enhancing scintillation efficiency.^{18,19}

Promising results in YAG:Ce have been obtained through dual Ca^{2+} – Mg^{2+} codoping.³ In these studies, Ce^{3+} absorption intensity decreased nearly to zero, while the shortest scintillation decay time of 26 ns was observed in a sample where approximately 4% of Ce remained in the trivalent state. Based on ionic radii $r(Ca^{2+}) = 0.112$ nm (8-fold coordination) and $r(Mg^{2+}) = 0.072$ nm (6-fold coordination)—

Ca^{2+} is expected to preferentially occupy dodecahedral Y^{3+} sites ($r(Y^{3+}) = 0.102$ nm), while Mg^{2+} is likely to replace octahedral Al^{3+} sites ($r(Al^{3+}) = 0.054$ nm). This selective incorporation enables precise control over defect structure and concentration in these sublattices.

Despite these advances, further reduction of the effective decay time below 26 ns has proven challenging.³ However, a decay time of 21 ns was reported for Al/Ga-substituted YAGG:Ce,Ca,⁴¹ while ultrafast decay times below 1 ns were achieved in Al/Ga-substituted GAGG:Ce,Mg (ref. 42) through a combination of bandgap engineering and divalent cation doping. These findings highlight the potential of Sc-doped YAG:Ce as an alternative to Ga doping, particularly when combined with Ca^{2+} – Mg^{2+} codoping. Further investigation into the interplay between Sc^{3+} substitution and divalent cation doping is necessary to optimize the scintillation properties of these materials.

This work presents, for the first time, the crystal growth and characterization of $Y_3Al_{1-x}Sc_xA_3O_{12}$:Ce with Sc concentrations of $x = 0.05, 0.25$, and 1.25 . Additionally, YSAG:Ce was codoped with Ca^{2+} and Mg^{2+} to regulate the charge states of Ce ions and enhance carrier transfer to Ce^{3+}/Ce^{4+} luminescence centers. All crystals were grown using the Czochralski method under a reducing Ar + CO atmosphere in tungsten (W) crucibles.

2. Experiment

2.1 Crystal growth and sample preparation

Three sets of crystals were grown by the Czochralski method from 50 mm diameter W crucibles in Ar + CO reducing gas atmosphere. Details of the Czochralski process under these conditions may be found elsewhere.^{7,8} The melt compositions were $(Y_{1-y-z}Ce_{0.01}Ca_yMg_z)_3Al_{2-x}Sc_xAl_3O_{12}$ ($x = 0.01, 0.05, 0.25$; $y = 0, 0.0075, 0.01$; $z = 0, 0.0025$), corresponding to 1 at%, 5 at%, 25 at% Sc^{3+} in respect to the overall content of Al^{3+} ions (Table 1). The first set included YSAG:Ce crystals with the three mentioned Sc^{3+} concentrations. The second set involved crystals with the same Sc^{3+} concentrations codoped with 1 at% Ca^{2+} . In the third set, crystals with the same Sc concentrations as in the previous sets were codoped with 0.75 at% Ca^{2+} and 0.25 at% Mg^{2+} , as these dopant concentrations provided the best combination of light output and decay time in YAG:Ce,Ca, Mg.³ The pulling rate during growth was 1.7 mm h^{-1} , the

Table 1 Compositions of melts for crystal growth

| Crystal | Ce, at% | Sc, at% | Ca, at% | Mg, at% |
|----------------------------|---------|---------|---------|---------|
| YAG:1Ce,1Sc | 1 | 1 | — | — |
| YAG:1Ce,5Sc | 1 | 5 | — | — |
| YAG:1Ce,25Sc | 1 | 25 | — | — |
| YAG:1Ce,1Sc,1Ca | 1 | 1 | 1 | — |
| YAG:1Ce,5Sc,1Ca | 1 | 5 | 1 | — |
| YAG:1Ce,25Sc,1Ca | 1 | 25 | 1 | — |
| YAG:1Ce,1Sc,0.75Ca,0.25Mg | 1 | 1 | 0.75 | 0.25 |
| YAG:1Ce,5Sc,0.75Ca,0.25Mg | 1 | 5 | 0.75 | 0.25 |
| YAG:1Ce,25Sc,0.75Ca,0.25Mg | 1 | 25 | 0.75 | 0.25 |



crystal rotation speed was 10 rpm. The starting raw materials for growth were yttrium oxide, cerium oxide, magnesium oxide, calcium oxide, aluminum oxide, and scandium oxide of 99.99% purity, without prior solid-phase synthesis. Samples of $5 \times 5 \times 2 \text{ mm}^3$ with polished sides of $5 \times 5 \text{ mm}^2$ for optical and scintillation measurements were cut from the crystals and annealed in air atmosphere for 48 hours at 1500 °C at atmospheric pressure.

2.2 X-ray diffraction analysis

X-ray phase analysis of powders was carried out using a SmartLab SE X-ray diffractometer from Rigaku. The diffraction patterns were obtained using Cu-K α radiation at $U = 40 \text{ kV}$, $I = 50 \text{ mA}$. Data analysis was performed using the Rietveld method. Further, the crystal structure of $\text{Y}_3\text{Al}_{5-x}\text{Sc}_x\text{O}_{12}$ garnet was refined using the Rietveld technique. The refinements employed the following atomic positional coordinates in the cubic unit cell: Y^{3+} at the 24c site (1/8, 0, 1/4), Al/Sc at the 16a and 24d sites (0, 0, 0 and x , 0, 1/4), and O at the 96 h site (x , 0, z). The profile shape and width (FWHM) were modeled using a pseudo-Voigt function and the Caglioti relationship ($\text{FWHM}^2 = u \tan 2\theta + v \tan \theta + w$), while the background was approximated by linear interpolation between a set of background points with definable heights. During refinement, the following parameters were varied: zero shift, scale factor, peak width parameters (u , v , w), lattice parameters, positional coordinates, and thermal parameters. The composition was fixed at the nominal value. Refinements for each composition converged rapidly, typically within a few cycles.

2.3 Optical measurements

The absorption spectra of the samples were measured using a PerkinElmer LAMBDA 650 UV/vis spectrometer. The instrument provided with a deuterium and halogen lamp and covers the wavelength range of 190 nm to 900 nm. The light passes through a monochromator and then split into two branches. One of the monochromatic light beams, whose intensity can be tuned by means of an iris, traverses the crystal sample placed on a moving stage. The other beam is instead employed to monitor instrumentation drift during the acquisition. Both beams were focalized through a photomultiplier measuring their intensity.

The photoluminescence spectra as well as the photoluminescence excitation spectra of crystals were measured with Perkin Elmer LS55 automatic spectrofluorometer. The spectrofluorometer emits a tunable monochromatic beam of light onto a sample and measures the intensity of luminescence as a function of its wavelength.

2.4 Light output and scintillation decay

The pulse-height spectra of the samples were measured using a Hamamatsu R2059 PMT, an analogue attenuator, and a DT5720 CAEN digitizer working in charge integration mode. The PMT is biased at 2500 V, providing sufficient gain to resolve the charge of single photoelectron pulses. That allows

to convert the total charge of a scintillation event to photoelectrons produced. The number of photons impinging on the PMT is obtained by correcting for the average quantum efficiency of the PMT, computed as the weighted average of the scintillator's emission and the PMT's quantum efficiency. The crystals were wrapped in Teflon on all faces coupled with Rhodosil grease to the PMT window. The ^{137}Cs (662 keV) gamma radioactive source was used for excitation of scintillations. The whole setup was enclosed in a temperature controlled black box.

The scintillation decay curves were measured using a time correlated single photon counting (TCSPC) setup.⁴³ A pulse diode laser (Pico-Quant, PDL 800-B) was used as an excitation source of an X-ray tube XRT N5084 from Hamamatsu. It generated an X-ray beam with a continuous energy spectrum between 0 and 40 keV (with a $\approx 10 \text{ keV}$ mean energy). The beam was collimated on the tested sample with a brass plate, and its scintillation light was collected using a hybrid photomultiplier (HPM 100-07 Becker Hickl) working in TCSPC mode. A 420 nm long pass filter was placed in front of the hybrid photomultiplier to suppress air excitation contribution to the emission distributions. The measurements were done hitting the sample on one surface and detecting the emitted light from the same surface (reflection mode). The repetition rate of excitation pulse was 500 kHz, and the time window of registration was 1–2 μs , depending on the sample decay time. The signal of the hybrid PMT was then fed to an amplifier and timing discriminator and was then used as the stop signal of a time to digital converter, while the start was provided by an external trigger of the pulse diode laser. Scintillation time profile for each sample was mathematically described with a multi-exponential function:

$$f(t|\theta) = \sum_{i=1}^3 \rho_i \frac{\exp\left(-\frac{t-\theta}{\tau_{d,i}}\right) - \exp\left(-\frac{t-\theta}{\tau_{r,i}}\right)}{\tau_{d,i} - \tau_{r,i}} \cdot \Theta(t-\theta) + \varepsilon,$$

where $\tau_{r,i}$ and $\tau_{d,i}$ are the i -th components of the rise and decay time constants respectively, while ρ_i is the weight of the i -th component, θ is the instant above which the scintillation pulse starts and ε is the background. The scintillation pulse function defined above was then convoluted with the impulse response function (IRF) of the setup ($\approx 180 \text{ ps}$ FWHM) to fit the decay spectra obtained. The effective decay time was defined as:

$$\frac{1}{\tau_{d,\text{eff}}} = \sum_{i=1}^3 \frac{A_i}{\tau_{d,i}}.$$

3. Results

3.1 Crystal growth

Photos of some as-grown crystals are presented in the Fig. 1. The crystals had diameters of about 18 mm and lengths of up to 60 mm. The sets of Sc,Ce-codoped (Fig. 1a–c) and Sc,



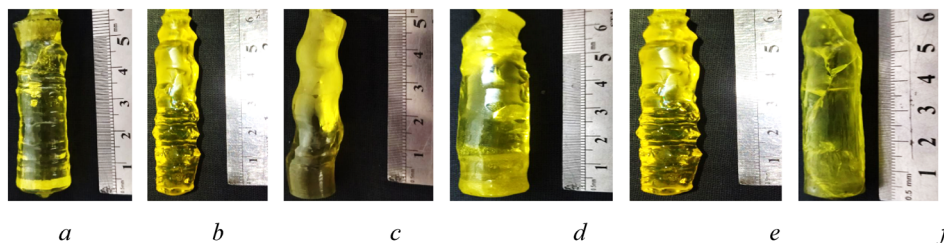


Fig. 1 As grown crystals from the melts with composition: (a) YAG:1Ce,1Sc, (b) YAG:1Ce,5Sc, (c) YAG:1Ce,25Sc, (d) YAG:1Ce,1Sc,1Ca, (e) YAG:1Ce,5Sc,1Ca, (f) YAG:1Ce,25Sc,1Ca.

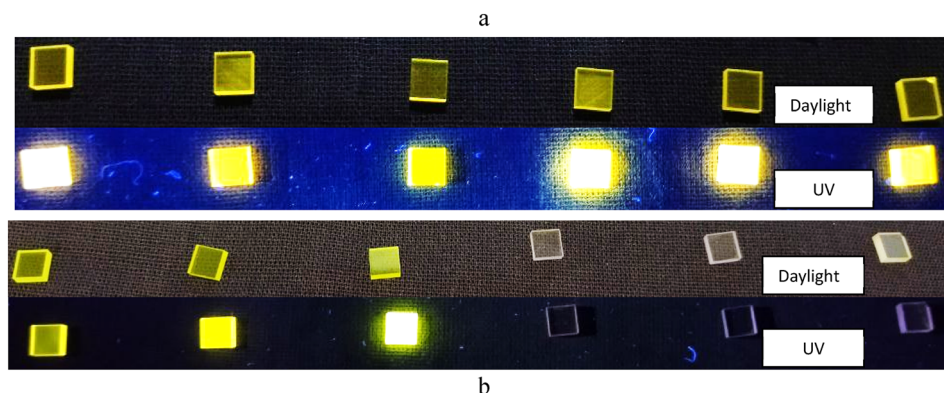


Fig. 2 Samples fabricated for optical and scintillation measurements (from left to right – YAG:1Ce,1Sc, YAG:1Ce,5Sc, YAG:1Ce,25Sc, YAG:1Ce,1Sc,1Ca, YAG:1Ce,5Sc,1Ca, YAG:1Ce,25Sc,1Ca) before (a) and after (b) annealing under daylight (top) and UV (bottom).

Ce,Ca-codoped (Fig. 1d–f) crystals contained few inclusions in the form of bubbles, while cracks were observed only in crystals with a large amount of scandium, see Fig. 1f.

Samples cut from the crystals before (Fig. 2a) and after annealing (Fig. 2b) under daylight and UV light are presented below. The Ca^{2+} -containing crystals became almost colorless after annealing, while the well-known yellow-green luminescence of Ce^{3+} -doped garnets was not observed under UV irradiation (Fig. 2a and b).

Mg-codoped crystals (Fig. 3) were not homogeneous in the entire bulk, with a large number of gas inclusions, apparently due to the dissociation of magnesium oxide in a reducing atmosphere and temperature of about 2000 °C.

Nevertheless, samples from transparent parts were produced (Fig. 4). Ca^{2+} - Mg^{2+} -codoped crystals had no coloration, except for the 25 at% Sc sample YAG:1Ce,25Sc,0.75Ca,0.25Mg. This may be due to the high Sc^{3+} concentrations preventing incorporation of Mg^{2+} into the crystal lattice and stabilizing Ce in the trivalent state.

3.2 Crystal structure and host composition

Fig. 5(a) presents the room temperature powder X-ray diffraction (PXRD) patterns of $\text{Y}_3\text{Al}_{5-x}\text{Sc}_x\text{O}_{12}$ garnet with $x = 0.05, 0.25,$ and 1.25 . The diffraction peaks in all patterns can be indexed to the cubic $Ia\bar{3}d$ space group, indicating a single-phase garnet structure. Notably, no impurity peaks are

observed in the PXRD patterns. A shift in the peak positions (see the example of the peak around 33.5° in Fig. 5(b)) towards lower 2θ values is observed with increasing Sc content, consistent with the larger ionic radius of Sc^{3+} (74.5 pm) compared to Al^{3+} (53.5 pm). This shift suggests an increase in lattice parameter and unit cell volume with increasing Sc^{3+} substitution. Sc^{3+} content was evaluated based on the lattice parameters of 12.01 Å in $\text{Y}_3\text{Al}_5\text{O}_{12}$ (ref. 44) and 12.271 Å in $\text{Y}_3\text{Al}_{5-x}\text{Sc}_x\text{O}_{12}$ (ref. 45) assuming a linear dependence between lattice parameters and Sc content. The Sc content in crystals is $x = 0.030, 0.245,$ and 1.234 at

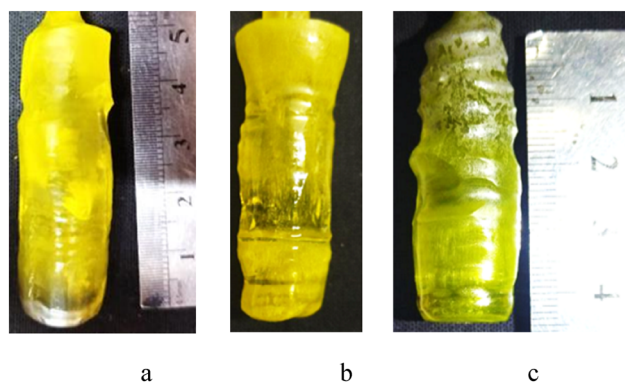


Fig. 3 As grown crystals from the melts with composition: (a) YAG:1Ce,1Sc,0.75Ca,0.25Mg, (b) YAG:1Ce,5Sc,0.75Ca,0.25Mg, (c) YAG:1Ce,25Sc,0.75Ca,0.25Mg.



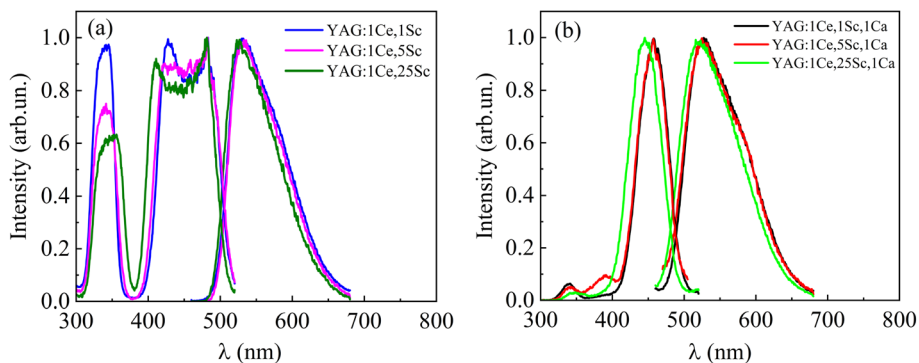


Fig. 7 Normalized photoluminescence excitation and emission spectra of crystals annealed in air: (a) YAG:Ce,Sc, $\lambda_{\text{ex}} = 350$ nm, $\lambda_{\text{em}} = 540$ nm, (b) YAG:Ce,Sc,Ca, $\lambda_{\text{ex}} = 440$ nm, $\lambda_{\text{em}} = 540$ nm.

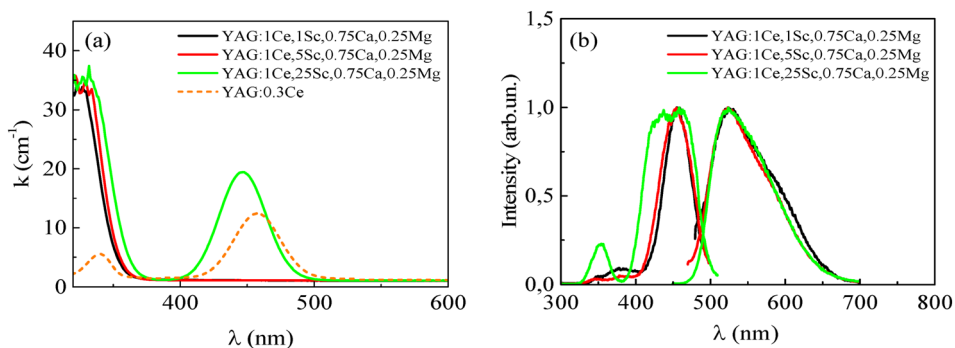


Fig. 8 (a) Absorption spectra of YAG:Ce,Sc,Ca,Mg crystals, (b) photoluminescence excitation spectra (left) and spectra (right) of YAG:Ce,Sc,Ca,Mg crystals annealed in air.

from the spectra of the Mg-free ones in the first two sets (see Fig. 6 and 7). No Ce^{3+} absorption was detected in the $\text{Ca}^{2+}\text{-Mg}^{2+}$ -codoped crystals with 1 and 5 at% of scandium, alongside with the strong absorption at $\lambda < 350$ nm attributed to the $\text{Ce}^{4+}\text{-O}^{2-}$ charge transfer complex (Fig. 8a). The behavior of luminescence emission and excitation curves of Ca–Mg-codoped crystals with 1 and 5 at% Sc is identical to those of the Mg-free crystals (see Fig. 7). In the luminescence excitation spectrum of the 25 at% Sc crystal, the band peaked at about 350 nm attributed to $4f\text{-}5d_2$ transition in Ce^{3+} is observed, which is typical for YAG:Ce

without codoping. Also, in the excitation spectra of samples with 1 and 5 at% of scandium (left black and red curves in Fig. 7b) there is the band of unknown nature in the region of 380 nm, which may be associated with impurities or defects.

3.4 Scintillation properties

Pulse-height spectra of YAG:Ce,Sc and YAG:Ce,Sc,Ca crystals presented in Fig. 9 display a clear trend to decrease in light output with Sc^{3+} concentration. The photopeak is clearly

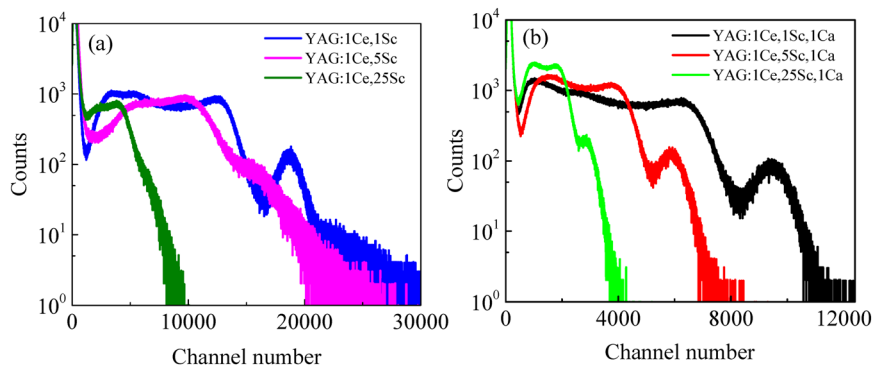


Fig. 9 Pulse-height spectra of the crystals: (a) YAG:Ce,Sc, (b) YAG:Ce,Sc,Ca under gamma quanta excitation by ^{137}Cs source with energy of 662 keV.



Table 2 Light output and luminescence decay parameters of the studied crystals. The most promising compositions are in bold

| Sample | LO, photon per MeV | τ_1 , ns | A_1 , % | τ_2 , ns | A_2 , % | τ_3 , ns | A_3 , % | τ_{eff} , ns | $(\tau_{\text{eff}}/\text{LO})^{1/2}$ |
|-----------------------------------|--------------------|---------------|------------|---------------|-------------|---------------|-------------|--------------------------|---------------------------------------|
| YAG:0.9Ce | 28 900 | 15.2 | 159.5 | 114.6 | 58.9 | 251.4 | 26.0 | 90.0 | 0.056 |
| YAG:1Ce,1Sc | 28 900 | 0.3 | 0.0 | 46.5 | 42.5 | 215.9 | 57.4 | 80.4 | 0.053 |
| YAG:1Ce,5Sc | 15 000 | 0.3 | 0.2 | 5.3 | 2.1 | 317.9 | 97.8 | 72.6 | 0.070 |
| YAG:1Ce,25Sc | ND | 0.2 | 0.5 | 4.0 | 3.33 | 253.8 | 96.2 | 21.7 | — |
| YAG:1Ce,1Sc,1Ca | 14 000 | 1.7 | 2.9 | 13.6 | 22.1 | 53.5 | 74.9 | 21.2 | 0.039 |
| YAG:1Ce,5Sc,1Ca | 8700 | 1.4 | 3.1 | 18.5 | 29.7 | 84.3 | 67.1 | 21.4 | 0.050 |
| YAG:1Ce,25Sc,1Ca | 3900 | 1.6 | 5.1 | 15.7 | 33.7 | 72.3 | 61.2 | 16.3 | 0.065 |
| YAG:1Ce,1Sc, 0.75Ca,0.25Mg | 18 000 | 2.5 | 2.7 | 16.9 | 22.9 | 54.3 | 74.4 | 25.88 | 0.038 |
| YAG:1Ce,5Sc, 0.75Ca,0.25Mg | 7660 | 2.3 | 4.6 | 20.7 | 34.9 | 84.8 | 60.5 | 22.49 | 0.054 |
| YAG:1Ce,25Sc, 0.75Ca,0.25Mg | 4000 | 1.9 | 3.2 | 16.6 | 28.0 | 72.0 | 68.8 | 23.11 | 0.076 |

distinguishable in all the Ca-containing crystals and YAG:1Ce,1Sc, while it is difficult to determine the precise photopeak position in the rest (Fig. 9a). The values of light output are summarized in Table 2. The highest light output of 28 900 photons per MeV is registered in the YAG:1Ce,1Sc crystal. This value almost coincides with the light output of the YAG:Ce crystal,¹ grown from a tungsten crucible under the same conditions. The lowest light output of approximately 3900 photons per MeV was registered for YAG:1Ce,25Sc,1Ca sample.

The luminescence decay curves under X-ray excitation (Fig. 10) and the values of luminescence decay times given in Table 2 suggest that codoping with both Sc³⁺ and Ca²⁺ accelerate scintillation decay. Thus, a shortest τ_{eff} of 16.3 ns is achieved in the YAG:1Ce,25Sc,1Ca crystal. It should be noted that although the ultrafast subnanosecond component appears in the decay curves of the Ca-free crystals, they also have a very slow component with a lifetime of few hundred nanoseconds. Ca²⁺-codoping allows to suppress this slow component significantly.

Among the samples, YAG:1Ce,25Sc and YAG:1Ce,25Sc,1Ca crystals with the addition of 25 at% Sc in solid solution demonstrated the fastest luminescence decay. The light output, however, is remarkably reduced to 14 000 and 3900 photons per MeV, respectively, due to the proximity of the 5d₁ levels of Ce³⁺ and Ce⁴⁺ to the bottom of the conduction band and subsequent thermal ionization of electrons into the conduction band from these levels. These results are in line with numerous works demonstrated the drop of light

output with acceleration of luminescence decay in Ce-doped garnets, see for example.^{33–40} According to the pulse-height spectra of the YAG:Ce,Sc,Ca,Mg crystals (Fig. 11a), the light output decreases with increasing Sc³⁺ concentration, like in the two previous sets. Luminescence decay curves and corresponding luminescence decay times of Ca²⁺-Mg²⁺ codoped crystals were slightly slower than those in Mg-free crystals (Fig. 11b). Ca–Mg-codoped crystals practically do not differ from Mg-free counterparts in terms of light output, see Table 2.

Considering the combination of light output and decay time, for the evaluation of photon time density, which is proportional to coincidence time resolution,⁴⁸ one may use the square root of the decay time (τ_{eff}) to the light output (LO) ratio. The lowest $(\tau_{\text{eff}}/\text{LO})^{1/2}$ parameters, *i.e.* the best timing resolution were registered in YAG:1Ce,1Sc,1Ca and YAG:1Ce,5Sc,0.75Ca,0.25Mg (appear in bold in Table 2) where a light output of 14 000–18 000 photons per MeV is combined with the effective decay time of 21–26 ns, nearly reaching the target values for scintillators at future detectors at HL-LHC.¹

4. Discussion

The scintillation parameters of the obtained YAG:Ce crystals were compared with previously studied Sc-doped garnets (Table 3). Y₃Al_{2–x}Sc_xAl₃O₁₂:Ce with a Sc content of $x = 0.05$ f. u. exhibited the highest light yield of 14 000 photons per MeV along with a relatively fast effective decay time of 21 ns. In contrast, previously reported Sc-doped garnets (Table 3)

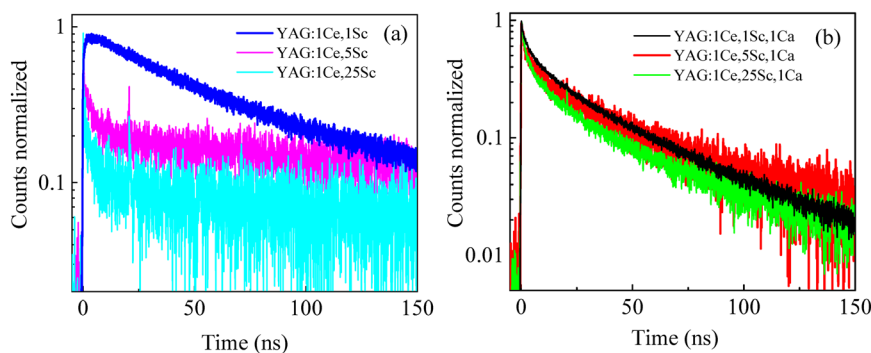


Fig. 10 Scintillation decay curves under X-ray excitation: (a) YAG:Ce,Sc, (b) YAG:Ce,Sc,Ca.



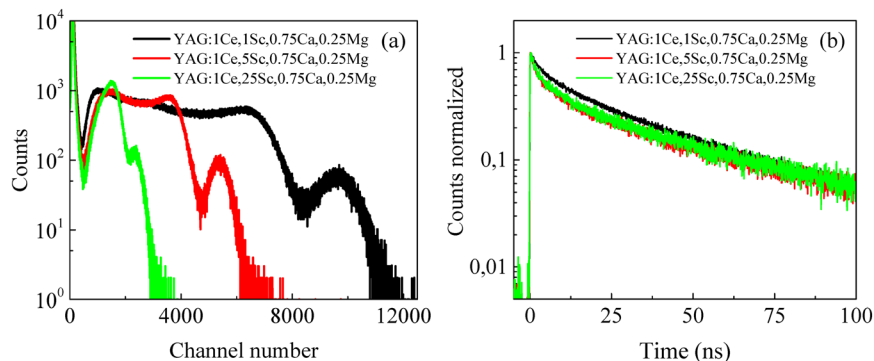


Fig. 11 (a) Pulse-height spectra of YAG:Ce,Sc,Ca,Mg crystals under excitation by gamma quanta from ^{137}Cs source with energy of 662 keV, (b) scintillation decay curves under X-ray excitation.

Table 3 Comparative properties of the studied YSAG:Ce,Ca crystals with other scandium-containing garnets

| Material | Sc content, f.u. | Light output, photon per MeV | Decay time, ns | Production method and ref. |
|--|------------------|------------------------------|----------------|----------------------------|
| GSAG:Ce,Mg | 1.89 | 10 160 | 120 | μ -PD ²³ |
| GYSAG:Ce,Mg | 1.9–2 | 3210 | 11.7 | μ -PD ²⁴ |
| GYSAG:Ce | 2 | 15 100 | 116 (fast) | μ -PD ²⁵ |
| GSAG:Ce,Mg | 2 | 555 | 19 | LPE ²⁶ |
| $\text{Lu}_2\text{Y}(\text{Al}_{5-x}\text{Sc}_x)\text{O}_{12}:\text{Ce},\text{Mg}$ | 1–2 | $\leq 35\%$ of BGO | 11–17 | LPE ²⁷ |
| GSAG:Ce,Mg | 1.89 | 2600–2800 | 94–175 (main) | FZ ²⁸ |
| GSAG:Ce | 1.89 | 10 240 | 46; 184 | Bridgman ²⁹ |
| GSAG:Ce,Mg | 1.89 | 9320 | 27; 92 | Bridgman ²⁹ |
| GSAG:Ce | 2 | 30% of NaI(Tl) | 120 | Czochralski ³² |
| YSAG:Ce,Ca | 0.05 | 14 000 | 21.2 | Czochralski (this work) |
| YSAG:Ce,Ca,Mg | 0.05 | 18 000 | 25.9 | Czochralski (this work) |

generally demonstrated lower light yield, likely due to high Sc^{3+} content (1.89–2 f.u.) in them, which induces strong thermal ionization from Ce^{3+} 5d levels. However, unlike Ga-doped garnets, the reduction in light yield in these works^{23–25,28,29,32} was not accompanied by a significant decrease in decay time. This supports the suggestion in ref. 25 that thermal quenching of Ce^{3+} at room temperature is not the primary cause of low light yield in the GSAG host. Instead, slow luminescence decay may be attributed to Sc-related traps.

Fast decay times of 11–19 ns were observed only in LPE-grown films,^{26,27} likely due to a lower concentration of intrinsic defects introduced during growth.⁴⁹ However, these films exhibited negligible light output. Sc^{3+} forms energy levels below the conduction band, reducing the electron ionization barrier from Ce^{3+} 5d₁ levels (which shifts by 0.14 eV under heavy Sc³⁺ doping in GSAG:Ce (ref. 22)). A high light yield observed in 1%-Sc-doped YSAG:Ce and YSAG:Ce, Ca in this study may be attributed to the relatively low Sc^{3+} content, which prevents the formation of a continuous subband merging with the conduction band and thus limits the electron ionization. Furthermore, Sc^{3+} situated at the dodecahedral site of the garnet lattice serves as a dominant electron trap, creating a bottleneck in the scintillation mechanism of GSAG:Ce.⁵⁰ Hence, a Sc^{3+} introduction to the dodecahedral sites should be negligible at a low Sc^{3+} content in YSAG:Ce, thus decreasing the possibility of such carrier

trapping. Both these factors contribute to a relatively high light output of 14 000–18 000 photons per MeV. This suggests that further optimization of scintillation parameters could be achieved by fine-tuning Sc and Ca concentrations in YSAG:Sc,Ce.

In contrast to YAG:Ce,Ca,Mg,³ Ca–Mg double codoping did not improve the scintillation performance of YSAG:Ce. This could be due to the competition between Mg^{2+} and Sc^{3+} ions for octahedral lattice sites, as both cations preferentially occupy these positions based on their ionic radii, thereby limiting Mg^{2+} incorporation into the lattice. Nevertheless, the Czochralski method appears promising for producing large Ce,Sc-codoped garnets with high optical quality and improved scintillation performance.

5. Conclusions

This study examined the impact of Sc and divalent cation (Ca^{2+} , Mg^{2+}) codoping on the optical and scintillation performance of YAG:Ce crystals. $(\text{Y}_{1-x-x}\text{Ce}_{0.01}\text{Ca}_y\text{Mg}_z)_3(\text{Al}_{1-x}\text{Sc}_x)_2\text{Al}_3\text{O}_{12}$ ($x = 0.01, 0.05, 0.25$; $y = 0, 0.0075, 0.01$; $z = 0, 0.0025$) crystals were grown by the Czochralski method using tungsten crucibles in a reducing Ar + CO atmosphere. Unlike gadolinium garnets, where Sc doping is typically constrained to 1.89–2 f.u.,^{23–26,28,29,32} we explored a broader Sc doping range of 0.05–1.25 f.u.



Our results indicate that codoping with Ca^{2+} and Sc^{3+} does not compromise crystal growth stability or optical quality under these conditions. However, additional Mg^{2+} codoping negatively impacted crystal quality. Unlike previous studies on GASG:Ce and GASGG:Ce scintillators, which exhibit low-to-moderate light yield and slow luminescence decay, our findings suggest that low-level Sc^{3+} doping in YAG:Ce allows fine control over electron thermal ionization from Ce^{3+} 5d levels while limiting carrier trapping on Sc^{3+} -related traps and preserving light output. Additionally, Ca^{2+} ions located near Ce^{3+} promote Ce^{4+} formation and enhance carrier transport to $\text{Ce}^{3+}/\text{Ce}^{4+}$ luminescence centers.

We identified an optimal codopant concentration yielding a high light output of 14000 photons per MeV and a short decay time of 21 ns in YAG:1 at%Ce, 1 at%Sc, 1 at%Ca. These parameters align with the requirements for radiation-hard inorganic scintillators in future HL-LHC detectors, where 25 ns particle collision intervals necessitate minimized pile-up. Further optimization of Sc and Ca content in YAG:Ce,Ca may enhance scintillation performance, offering a viable alternative to Gd-containing garnets. While YAG has a lower density ($\sim 2 \text{ g cm}^{-3}$ less than GSAG), this drawback can be mitigated in sampling calorimeters where scintillation fibers are embedded in a W absorber, ensuring most particle energy is attenuated by tungsten. Additionally, low Sc^{3+} content does not seriously increase crystal production cost, given the high cost of Sc_2O_3 raw material.

Data availability

The data supporting this article have been included as part of the ESI.†

Author contributions

Ia. Gerasymov – conceptualization, investigation, writing – original draft, writing – review & editing. S. Tkachenko – investigation, methodology. D. Kurtsev – investigation. D. Kofanov – investigation. O. Viahin – investigation, visualization, writing – review & editing. P. Maksimchuk – investigation, visualization. I. Rybalka – investigation. B. Grynyov – supervision. L. Martinazzoli – investigation, visualization. L. Roux – investigation. E. Auffray – management, writing – review & editing. A. Padmanaban – data curation. O. Sidletskiy – management, supervision, writing – review & editing.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was made in the frame of Horizon Europe ERA Widening Project no. 101078960 “TWISMA”, and supported by the Crystal Clear Collaboration and CERN EP-RD. A. Padmanaban and O. Sidletskiy acknowledge the support from

the project “Centre of Excellence in Nanophotonics, Advanced Materials and Technologies Based on Crystal Growth” (ENSEMBLE3) carried out within the International Research Agendas Program of the Foundation for Polish Science and Teaming for Excellence Project under grant MAB/2020/14 and grant 857543.

References

- O. Sidletskiy, Ia. Gerasymov, Y. Boyaryntseva, P. Arhipov, S. Tkachenko, O. Zelenskaya, K. Bryleva, K. Belikov, K. Lebbou, C. Dujardin, B. Buchner and B. Grynyov, *Cryst. Growth Des.*, 2021, **21**, 3063.
- M. Nikl, V. Babin, J. A. Mares, K. Kamada, S. Kurosawa, A. Yoshikawa, J. Tous, J. Houzvicka and K. Blazek, *J. Lumin.*, 2016, **169**, 539.
- O. Sidletskiy, Ia. Gerasymov, D. Kurtsev, O. Viahin, S. Tkachenko, D. Kofanov, S. Sadvynycha, L. Martinazzoli, L. Roux, E. Auffray, V. Kononets and K. Lebbou, Progress in fast-timing Ce-doped garnet scintillators by complex codoping with divalent cations, *Mater. Res. Bull.*, 2025, **184**, 113283.
- E. Auffray, A. Fedorov, V. Dormenev, J. Houzvička, M. Korjik, M. T. Lucchini, V. Mechinsky and S. Ochescu, Optical transmission damage of undoped and Ce doped Y3Al5O12 scintillation crystals under 24 GeV protons high fluence, *Nucl. Instrum. Methods Phys. Res., Sect. A*, 2017, **856**, 7.
- V. Dormenev, K.-T. Brinkmann, A. Borisevich, D. Kazlou, M. Korzhik, M. Moritz, R. W. Novotny, P. Orsich, Ia. Gerasymov, S. Tkachenko, P. Arhipov, O. Sidletskiy and H.-G. Zaunick, Radiation tolerant YAG: Ce scintillation crystals grown under reducing Ar + CO atmosphere, *Nucl. Instrum. Methods Phys. Res., Sect. A*, 2021, **1015**, 165764.
- J. Houzvička and K. Bartoš, Method for the preparation of doped garnet structure single crystals with diameters of up to 500 mm (CRYTUR, SPOL, SRO), *US Pat.*, 9499923B2, 2016.
- P. Arhipov, S. Tkachenko, S. Vasiukov, K. Hubenko, Ia. Gerasymov, V. Baumer, A. Puzan, P. Mateychenko, K. Lebbou and O. Sidletskiy, *J. Cryst. Growth*, 2016, **449**, 104.
- O. Sidletskiy, P. Arhipov, S. Tkachenko, Ia. Gerasymov, D. Kurtsev, V. Jary, R. Kucerkova, M. Nikl, K. Lebbou and E. Auffray, *Springer Proceedings in Physics*, 2019, vol. 227, p. 83.
- DRD 6: Calorimetry, Proposal Team For DRD-on-Calorimetry, CERN, 2024, July 31, <https://cds.cern.ch/record/2886494/files/DRD6-cdscern.pdf?version=3>.
- P. Lecoq, C. Morel, J. O. Prior, D. Visvikis, S. Gundacker, E. Auffray, P. Križan, R. M. Turtos, D. Thers and E. Charbon, Roadmap toward the 10 ps time-of-flight PET challenge, *Phys. Med. Biol.*, 2020, **65**, 21RM01.
- O. Sidletskiy, P. Arhipov, S. Tkachenko, O. Zelenskaya, S. Vasyukov, F. Moretti and C. Dujardin, *Phys. Status Solidi A*, 2018, **215**, 1800122.
- M. Moszynski, T. Ludziejewski, D. Wolski, W. Klamra and L. O. Norlin, *Nucl. Instrum. Methods Phys. Res., Sect. A*, 1994, **345**, 461.



- 13 E. Mihokova, M. Nikl, J. A. Mares, A. Beitlerova, A. Vedda, K. Nejezchleb, K. Blazek and C. D'Ambrosio, *J. Lumin.*, 2007, **126**, 77.
- 14 C. Parkes and R. Lindner, Framework TDR for the LHCb Upgrade II: Opportunities in flavour physics, and beyond, in the HL-LHC era, CERN-LHCC-2021-012; LHCb-TDR-023.
- 15 M. M. Kuklja, Defects in yttrium aluminium perovskite and garnet crystals: atomistic study, *J. Phys.: Condens. Matter*, 2000, **12**, 2953.
- 16 S. Jiang, T. Lu and J. Chen, Ab initio study the effects of Si and Mg dopants on point defects and Y diffusion in YAG, *Comput. Mater. Sci.*, 2013, **69**, 261.
- 17 J. Zhu, O. Sidletskiy, Y. Boyarintseva and B. Grynyov, *Opt. Mater.*, 2021, **111**, 110561.
- 18 L. Jia, J. Zhu, Y. Boyarintseva, Ia. Gerasymov, B. Grynyov and O. Sidletskiy, *Phys. Status Solidi B*, 2021, **258**(12), 2100325.
- 19 L. Jia, M. Gu, J. Zhu, B. Grynyov and O. Sidletskiy, Influence of Carbon Doping on Stability of Intrinsic Defects in Y3Al5O12 and Lu3Al5O12, *Phys. Status Solidi B*, 2024, 2300544.
- 20 V. Babin, P. Bohacek, M. Nikl, L. Vasylechko and S. Zazubovich, Influence of {Ce3+ - Mg2+} pairs on the photo- and thermally stimulated luminescence of Mg2+ co-doped Gd3(Ga,Al)5O12:Ce single crystals, *Opt. Mater.*, 2024, **154**, 115691.
- 21 V. Babin, P. Bohacek, A. Krasnikov, M. Nikl, L. Vasylechko and S. Zazubovich, Photoluminescence optical and thermal quenching in heavily doped Gd3(Ga, Al)5O12:Ce, Mg single crystals: Dependence on the Ga3+, Ce3+, and Mg2+ concentration, *J. Lumin.*, 2025, **277**, 120945.
- 22 D. Spassky, N. Kozlova, E. Zabelina, V. Kasimova, N. Krutyak, A. Ukhanova, V. A. Morozov, A. V. Morozov, O. Buzanov, K. Chernenko, S. Omelkov and V. Nagirnyi, Influence of the Sc cation substituent on the structural properties and energy transfer processes in GAGG:Ce crystals, *CrystEngComm*, 2020, **22**, 2621.
- 23 O. Zapadlík, J. Pejchal, R. Kučerková, A. Beitlerová and M. Nikl, Composition-Engineered GSAG Garnet: Single-Crystal Host for Fast Scintillators, *Cryst. Growth Des.*, 2021, **21**, 7139.
- 24 O. Zapadlík, J. Pejchal, F. Levchenko, R. Kucerova, A. Beitlerova, V. Vanecek, K. Jurek and M. Nikl, The Ga-admixed GSAG:Ce single crystal scintillator: Composition tuning, *J. Lumin.*, 2023, **263**, 119984.
- 25 O. Zapadlík, J. Pejchal, V. Babin, V. Jary, V. Vanecek, R. Kucerova, K. Jurek, A. Beitlerova and M. Nikl, GSAG:Ce scintillator: insights from yttrium admixture, *RSC Adv.*, 2025, **15**, 2140.
- 26 K. Wantong, W. Chewpraditkul, W. Chewpraditkul, M. Rathaiah, M. Kucera, S. Danis, A. Beitlerovac, R. Kucerovac and M. Nikl, Optical, luminescence and scintillation characteristics of Gd3Sc2(Al3-xGax)O12: Ce,Mg (x = 0, 1, 2) single crystalline films, *Opt. Mater.*, 2022, **134**, 113240.
- 27 W. Chewpraditkul, K. Wantong, W. Chewpraditkul, N. Pattanaboonmee, R. Kucerova, A. Beitlerova, M. Nikl, D. Strachotova and M. Kucera, Effects of Sc3+ admixture on luminescence and scintillation properties of Ce3+-doped Lu2Y(Al5-xScx)O12 (x = 1, 1.5, 2) garnet single-crystalline films, *Opt. Mater.*, 2023, **145**, 114417.
- 28 F. Zajíc, J. Pospíšil, R. Kučerková, P. Boháček and M. Nikl, Growth of GSAG:Ce scintillator by floating zone method under pressurized oxygen atmosphere, *J. Cryst. Growth*, 2024, **627**, 127479.
- 29 K. L. Hovhannesian, M. V. Derdzyan, G. Badalyan, G. Kharatyan, J. Pejchal, M. Nikl, C. Dujardin and A. G. Petrosyan, *CrystEngComm*, 2024, **26**, 4812.
- 30 C. D. Brandle and R. L. Barns, Crystal Stoichiometry and Growth of Rare-earth Garnets Containing Scandium, *J. Cryst. Growth*, 1973, **20**, 1.
- 31 G. B. Lutts, A. L. Denisov, E. V. Zharikov, A. I. Zagumennyi, S. N. Kozlikin, S. V. Lavrishchev and S. A. Samoylova, GSAG and YSAG: A Study on Isomorphism and Crystal Growth, *Opt. Quantum Electron.*, 1990, **22**, S269.
- 32 A. Kling, D. Kollwe and D. Mateika, Scintillation properties of cerium-doped gadolinium-scandium-aluminum garnets, *Nucl. Instrum. Methods Phys. Res., Sect. A*, 1994, **346**, 205.
- 33 M. Nikl, K. Kamada, V. Babin, J. Pejchal, K. Pilarova, E. Mihokova, A. Beitlerova, K. Bartosiewicz, Sh. Kurosawa and A. Yoshikawa, *Cryst. Growth Des.*, 2014, **14**, 4827.
- 34 V. Laguta, L. Havlak, V. Babin, J. Barta, J. Pejchal and M. Nikl, *Materials*, 2023, **12**, 4488.
- 35 M. Tyagi, F. Meng, M. Koschan, S. B. Donald, H. Rothfuss and C. Melcher, *J. Phys. D: Appl. Phys.*, 2013, **46**, 475302.
- 36 W. Chewpraditkul, N. Pattanaboonmee, O. Sakthong, K. Wantong, W. Chewpraditkul, A. Yoshikawa, K. Kamada, S. Kurosawa, T. Szczesniak, M. Moszynski, V. Babin and M. Nikl, *Opt. Mater.*, 2019, **92**, 181.
- 37 Ia. Gerasymov, S. Witkiewicz-Lukaszek, T. Zorenko, K. Bartosiewicz, Yu. Zorenko, J. Winiecki, D. Kofanov, Y. Boyarintseva, S. Tkachenko, P. Arhipov, E. Galenen, D. Kurtsev, O. Zelenskaya, V. Alekseev, K. Lebbou and O. Sidletskiy, *IEEE Trans. Nucl. Sci.*, 2023, **70**(7), 1362.
- 38 V. Kononets, K. Lebbou, O. Sidletskiy, Yu. Zorenko, M. Lucchini, K. Pauwels and E. Auffray, *Springer Proc. Phys.*, 2016, **200**, 114.
- 39 S. Liu, J. A. Mares, X. Feng, A. Vedda, M. Fasoli, Y. Shi, H. Kou, A. Beitlerova, L. Wu, C. D'Ambrosio, Y. Pan and M. Nikl, *Adv. Opt. Mater.*, 2016, **4**, 731.
- 40 F. Moretti, K. Hovhannesian, M. Derdzyan, G. A. Bizarri, E. D. Bourret, A. G. Petrosyan and C. Dujardin, *ChemPhysChem*, 2017, **18**(5), 493.
- 41 O. Sidletskiy, Ia. Gerasymov, D. Kurtsev, V. Kononets, V. Pedash, O. Zelenskaya, V. Tarasov, A. Gektin, B. Grynyov, K. Lebbou, E. Auffray, V. Dormenev, A. Borisevich and M. Korjik, *CrystEngComm*, 2017, **19**(6), 1001.
- 42 L. Martinazzoli, S. Nargelas, P. Boháček, R. Calá, M. Dušek, J. Rohlíček, G. Tamulaitis, E. Auffray and M. Nikl,



- Compositional engineering of multicomponent garnet scintillators: towards an ultra-accelerated scintillation response, *Mater. Adv.*, 2022, **3**, 6842.
- 43 F. Pagano, N. Kratochwil, I. Frank, S. Gundacker, M. Paganoni, M. Pizzichemi, M. Salomoni and E. Auffray, A new method to characterize low stopping power and ultra-fast scintillators using pulsed X-rays, *Front. Phys.*, 2022, **10**, 1021787, DOI: [10.3389/fphy.2022.1021787](https://doi.org/10.3389/fphy.2022.1021787).
- 44 K. Yasuhiko, K. Suda, N. Ishizawa and T. Yamada, Crystal growth and properties of (Lu, Y) $3\text{Al}_5\text{O}_{12}$, *J. Cryst. Growth*, 2004, **260**, 159.
- 45 T. H. Allik, C. A. Morrison, J. B. Gruber and M. R. Kokta, Crystallography, spectroscopic analysis, and lasing properties of $\text{Nd}^{3+}:\text{Y}_3\text{Sc}_2\text{Al}_3\text{O}_{12}$, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1990, **41**, 21.
- 46 P. Dorenbos, *J. Lumin.*, 2000, **91**(3), 155.
- 47 Yu. Zorenko, T. Zorenko, P. Malinowski, O. Sidletskiy and S. Neicheva, Luminescent properties of $\text{Y}_3\text{Al}_{5-x}\text{Ga}_x\text{O}_{12}:\text{Ce}$ crystals, *J. Lumin.*, 2014, **156**, 102.
- 48 S. Vinogradov, Approximations of coincidence time resolution models of scintillator detectors with leading edge discrimination, *Nucl. Instrum. Methods Phys. Res., Sect. A*, 2018, **912**, 149.
- 49 Yu. Zorenko, V. Gorbenko, I. Konstankevych, A. Voloshinovskii, G. Stryganyuk, V. Mikhailin, V. Kolobanov and D. Spassky, *J. Lumin.*, 2005, **114**, 85.
- 50 M. Nikl, J. Pejchal, J. Jezek, D. Sedmibudsky, V. Laguta, V. Babin, A. Beitlerova and R. Kucerkova, GSAG:Ce scintillator: material optimization and intrinsic bottlenecks, *Mater. Adv.*, 2025, DOI: [10.1039/d5ma00095e](https://doi.org/10.1039/d5ma00095e).

